

Thyristor High Voltage, Phase Control SCR, 30 A



PRIMARY CHARACTERISTICS					
I _{T(AV)}	20 A				
V _{DRM} /V _{RRM}	1600 V				
V _{TM}	1.3 V				
I _{GT}	45 mA				
TJ	-40 °C to +125 °C				
Package	TO-247AD 3L				
Circuit configuration	Single SCR				

FEATURES

- Designed and qualified according to JEDEC® - JESD 47
- Flexible solution for reliable AC power rectification



- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

DESCRIPTION

The VS-30TPS16L-M3 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. AEC-Q101 qualified P/N available (VS-30TPS16LHM3).

PARAMETER	TEST CONDITIONS	VALUES	UNITS
I _{T(AV)}	Sinusoidal waveform	20	Δ.
I _{RMS}		30	A
V _{RRM} /V _{DRM}		1600	V
I _{TSM}		300	А
V _T	20 A, T _J = 25 °C	1.3	V
dv/dt		500	V/µs
di/dt		150	A/µs
T _J		-40 to +125	°C

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA				
VS-30TPS16L-M3	1600	1700	10				



ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
Maximum average on-state current	I _{T(AV)}	T _C = 95 °C, 180° conduction	half sine wave	20			
Maximum RMS on-state current	I _{RMS}			30	Α		
Maximum peak, one-cycle,	I	10 ms sine pulse, rated V _{RRM}	applied	250	^		
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage	reapplied	300			
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM}	applied	310	A ² s		
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied		442	A-5		
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied		4420	A²√s		
Maximum on-state voltage drop	V_{TM}	20 A, T _J = 25 °C		1.3	V		
On-state slope resistance	r _t	T _{.1} = 125 °C		12	mΩ		
Threshold voltage	V _{T(TO)}	1j = 125 C		1.0	V		
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 25 °C	V _R = rated V _{RRM} /V _{DRM}	0.5			
waximum reverse and direct leakage current	'RM/ 'DM	T _J = 125 °C	VR - rated VRRM/ VDRM	10	mA		
Maximum holding current	I _H	Anode supply = 6 V, resistive load, initial $I_T = 1$ A, $T_J = 25$ °C		150	ША		
Maximum latching current	ΙL	Anode supply = 6 V, resistive load, T _J = 25 °C		200			
Maximum rate of rise of off-state voltage	dv/dt	$T_J = T_J$ maximum, linear to 80 % V_{DRM} , R_g - k = open		500	V/µs		
Maximum rate of rise of turned-on current	di/dt			150	A/μs		

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	P _{GM}		8.0	W	
Maximum average gate power	P _{G(AV)}		2.0	VV	
Maximum peak positive gate current	+I _{GM}		1.5	Α	
Maximum peak negative gate voltage	-V _{GM}		10	V	
	I _{GT}	Anode supply = 6 V, resistive load, T _J = -10 °C	60	mA	
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, $T_J = 25$ °C	45		
		Anode supply = 6 V, resistive load, T _J = 125 °C	20		
Maximum required DC gate		Anode supply = 6 V, resistive load, T _J = -10 °C	2.5		
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, $T_J = 25 ^{\circ}\text{C}$	2.0	v	
voltage to trigger		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V	
Maximum DC gate voltage not to trigger	V_{GD}	T. = 125 °C V = rated value	0.25		
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = rated value	2.0	mA	

SWITCHING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9				
Typical reverse recovery time	t _{rr}	T _{.l} = 125 °C	4	μs			
Typical turn-off time	t _q	IJ = 125 C	110				



THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to 125	°C		
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	0.8			
Maximum thermal resistance, junction to ambient	R _{thJA}		'		°C/W		
Maximum thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.25			
Approximate weight				6	g		
Approximate weight				0.21	OZ.		
Mounting torque	minimum			6 (5)	kgf · cm		
- Wounting torque	maximum			12 (10)	(lbf · in)		
Marking device Case style TO-247AD 3L 30TPS		S16L					

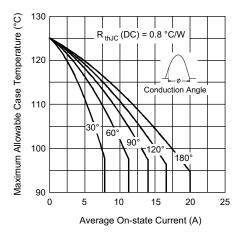


Fig. 1 - Current Rating Characteristics

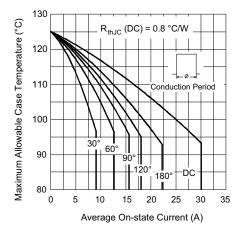


Fig. 2 - Current Rating Characteristics

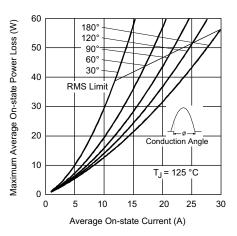


Fig. 3 - On-State Power Loss Characteristics

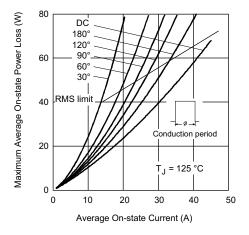


Fig. 4 - On-State Power Loss Characteristics



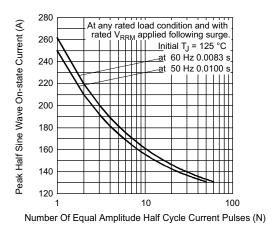


Fig. 5 - Maximum Non-Repetitive Surge Current

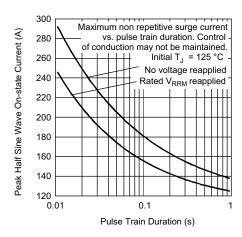


Fig. 6 - Maximum Non-Repetitive Surge Current

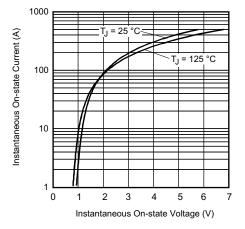


Fig. 7 - On-State Voltage Drop Characteristics

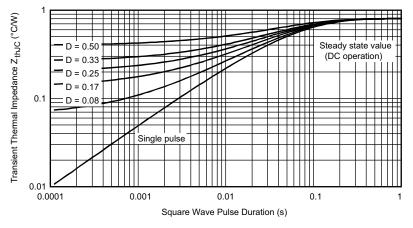


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



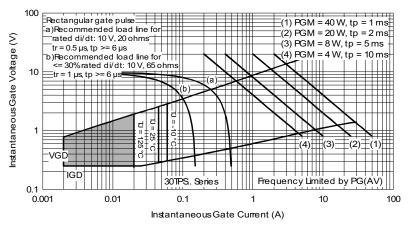
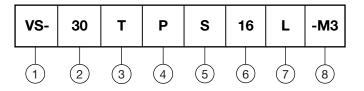


Fig. 9 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (30 = 30 A)

3 - Circuit configuration:

T = thyristor

4 - Package:

P = TO-247

5 - Type of silicon:

S = standard recovery rectifier

6 - Voltage rating (16 = 1600 V)

7 - Package L = long lead

8 - Environmental digit:

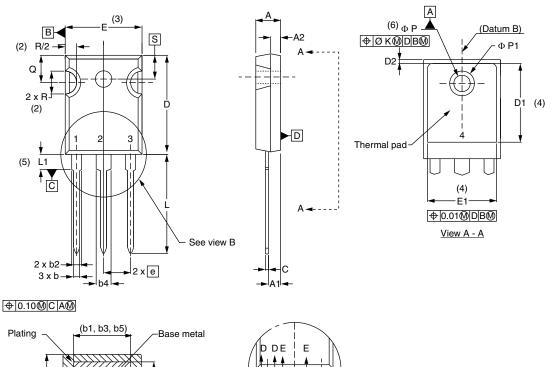
-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-30TPS16L-M3	25	500	Antistatic plastic tubes				

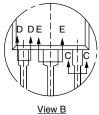
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95626</u>				
Part marking information	www.vishay.com/doc?95007			

TO-247AD 3L

DIMENSIONS in millimeters and inches



Plating _	(b1, b3, b5)	-Base meta
(c)		c1
	(b, b2, b4) — (4)	
9	Section C - C, D - D	<u>, E - E</u>



CVMPOL	SYMBOL MILLIMETERS INCHES		NOTES		
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	IVIILLIIV	IEIENO	INCHES		NOTES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	2.54		0.0)10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	' BSC	

INCHES

MILLIMETERS

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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